





SBOS135C – JANUARY 1984 – REVISED AUGUST 2005

# Ultra-Low Noise, Precision OPERATIONAL AMPLIFIERS

## **FEATURES**

- LOW NOISE: 4.5nV/√Hz max at 1kHz
- LOW OFFSET: 100μV max
- LOW DRIFT: 0.4µV/°C
- HIGH OPEN-LOOP GAIN: 117dB min
- HIGH COMMON-MODE REJECTION: 100dB min
- HIGH POWER-SUPPLY REJECTION: 94dB min
- FITS OP-07, OP-05, AD510, AND AD517 SOCKETS

## APPLICATIONS

- PRECISION INSTRUMENTATION
- DATA ACQUISITION
- TEST EQUIPMENT
- PROFESSIONAL AUDIO EQUIPMENT
- TRANSDUCER AMPLIFIERS
- RADIATION HARD EQUIPMENT

## DESCRIPTION

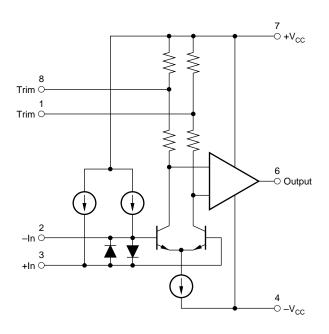
The OPA27 and OPA37 are ultra-low noise, high-precision monolithic operational amplifiers.

Laser-trimmed thin-film resistors provide excellent long-term voltage offset stability and allow superior voltage offset compared to common zener-zap techniques.

A unique bias current cancellation circuit allows bias and offset current specifications to be met over the full  $-40^{\circ}$ C to  $+85^{\circ}$ C temperature range.

The OPA27 is internally compensated for unity-gain stability. The decompensated OPA37 requires a closed-loop gain  $\geq$  5.

The Texas Instruments' OPA27 and OPA37 are improved replacements for the industry-standard OP-27 and OP-37.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage	±22V
Internal Power Dissipation (2)	500mW
Input Voltage	±V <sub>CC</sub>
Output Short-Circuit Duration (3)	
Differential Input Voltage (4)	±0.7V
Differential Input Current (4)	±25mA
Storage Temperature Range	–55°C to +125°C
Operating Temperature Range	40°C to +85°C
Lead Temperature:	
P (soldering, 10s)	+300°C
U (soldering, 3s)	+260°C

NOTES: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. (2) Maximum package power dissipation versus ambient temperature. (2) To common with  $\pm V_{CC} = 15V$ . (4) The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds  $\pm 0.7V$ , the input current should be limited to 25mA.

### PACKAGE/ORDERING INFORMATION<sup>(1)</sup>

PRODUCT	PACKAGE-LEAD	$ heta_{JA}$	PACKAGE DRAWING	PACKAGE MARKING
OPA27	DIP-8	100°C/W	P	OPA27GP
OPA27	SO-8	160°C/W	D	OPA27U
OPA37	DIP-8	100°C/W	P	OPA37GP
OPA37	SO-8	160°C/W	D	OPA37U

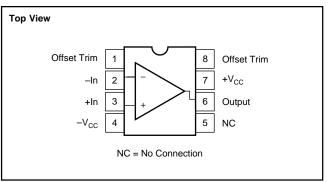
NOTE: (1) For the most current package and ordering information, see the Package Option Addendum located at the end of this document, or see the TI website at www.ti.com.

# ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### PIN CONFIGURATION





# **ELECTRICAL CHARACTERISTICS**

At  $V_{CC} = \pm 15V$  and  $T_A = +25^{\circ}C$ , unless otherwise noted.

			OPA27 OPA37		
PARAMETER	CONDITIONS	MIN	TYP	МАХ	UNITS
INPUT NOISE <sup>(6)</sup>					
Voltage, f <sub>O</sub> = 10Hz			3.8	8.0	nV/√Hz
$f_0 = 30Hz$			3.3	5.6	nV/√Hz
$f_0 = 1 kHz$			3.2	4.5	nV/√Hz
$f_B = 0.1$ Hz to 10Hz			0.09	0.25	μV <sub>PP</sub>
Current, <sup>(1)</sup> $f_0 = 10Hz$			1.7		pA/√Hz
$f_0 = 30Hz$			1.0 0.4	0.6	pA/√Hz pA/√Hz
$f_{O} = 1 \text{kHz}$		_	0.4	0.6	pA/vnz
OFFSET VOLTAGE <sup>(2)</sup>			105		
Input Offset Voltage	T (1 T		±25	±100	μV
Average Drift <sup>(3)</sup>	$T_{A MIN}$ to $T_{A MAX}$		±0.4	±1.8 <sup>(6)</sup>	μV/°C
Long Term Stability <sup>(4)</sup>			0.4	2.0	μV/mo
Supply Rejection	$\pm V_{CC} = 4$ to 18V	94	120		dB
	$\pm V_{CC} = 4$ to 18V		±1	±20	μV/V
BIAS CURRENT					
Input Bias Current			±15	±80	nA
OFFSET CURRENT					
Input Offset Current			10	75	nA
IMPEDANCE					
Common-Mode		_	2    2.5		GΩ    pF
		144	140.0		V
Common-Mode Input Range Common-Mode Rejection	$V_{IN} = \pm 11 VDC$	±11 100	±12.3 122		dB
·					-
OPEN-LOOP VOLTAGE GAIN, DC	$R_{L} \ge 2k\Omega$ $R_{L} \ge 1k\Omega$	117	124 124		dB dB
FREQUENCY RESPONSE					
Gain-Bandwidth Product <sup>(5)</sup>	OPA27	5 (6)	8		MHz
	OPA37	45 <sup>(6)</sup>	63		MHz
Slew Rate <sup>(5)</sup>	$V_O = \pm 10V$ ,				
	$R_L = 2k\Omega$				
	OPA27, G = +1	1.7 (6)	1.9		V/µs
	OPA37, G = +5	11 <sup>(6)</sup>	11.9		V/µs
Settling Time, 0.01%	OPA27, G = +1 OPA37, G = +5		25 25		μs μs
RATED OUTPUT	01 A37, 0 = +3		23		μο
Voltage Output	$R_{L} \ge 2k\Omega$	±12	±13.8		V
	$R_{\rm L} \ge 600\Omega$	±12 ±10	±12.8		v
Output Resistance	DC, Open Loop		70		Ω
Short Circuit Current	$R_L = 0\Omega$		25	60 <sup>(6)</sup>	mA
POWER SUPPLY					
Rated Voltage			±15		VDC
Voltage Range,					
Derated Performance		±4		±22	VDC
Current, Quiescent	I <sub>O</sub> = 0mADC		3.3	5.7	mA
TEMPERATURE RANGE					
Specification		-40		+85	°C
Operating		-40		+85	°C

NOTES: (1) Measured with industry-standard noise test circuit (Figures 1 and 2). Due to errors introduced by this method, these current noise specifications should be used for comparison purposes only. (2) Offset voltage specification are measured with automatic test equipment after approximately 0.5 seconds from power turnon. (3) Unnulled or nulled with 8kΩ to 20kΩ potentiometer. (4) Long-term voltage offset vs time trend line does not include warm-up drift. (5) Typical specification only on plastic package units. Slew rate varies on all units due to differing test methods. Minimum specification applies to open-loop test. (6) This parameter specified by design.





# ELECTRICAL CHARACTERISTICS (Cont.)

At  $V_{CC}$  =  $\pm 15V$  and  $-40^{\circ}C \leq T_{A} \leq +85^{\circ}C,$  unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
INPUT VOLTAGE <sup>(1)</sup> Input Offset Voltage Average Drift <sup>(2)</sup> Supply Rejection	$ \begin{array}{l} T_{A \; MIN} \; \text{to} \; T_{A \; MAX} \\ \pm V_{CC} = 4.5 \; \text{to} \; 18V \\ \pm V_{CC} = 4.5 \; \text{to} \; 18V \end{array} $	90 <sup>(3)</sup>	±48 ±0.4 122	±220 <sup>(3)</sup> ±1.8 <sup>(3)</sup>	μV μV/°C dB
BIAS CURRENT Input Bias Current			±21	±150 <sup>(3)</sup>	nA
OFFSET CURRENT Input Offset Current			20	135 <sup>(3)</sup>	nA
VOLTAGE RANGE Common-Mode Input Range Common-Mode Rejection	V <sub>IN</sub> = ±11VDC	±10.5 <sup>(3)</sup> 96 <sup>(3)</sup>	±11.8 122		V dB
OPEN-LOOP GAIN, DC Open-Loop Voltage Gain	$R_L \ge 2k\Omega$	113 <sup>(3)</sup>	120		dB
RATED OUTPUT Voltage Output Short Circuit Current	$R_L = 2k\Omega$ $V_O = 0VDC$	±11.0 <sup>(3)</sup>	±13.4 25		V mA
TEMPERATURE RANGE Specification		-40		+85	°C

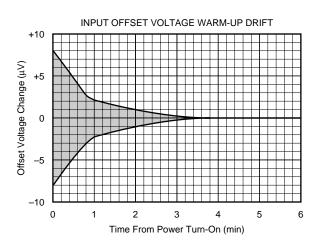
NOTES: (1) Offset voltage specification are measured with automatic test equipment after approximately 0.5s from power turn-on. (2) Unnulled or nulled with 8kΩ to 20kΩ potentiometer. (3) This parameter specified by design.

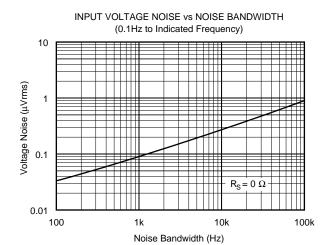




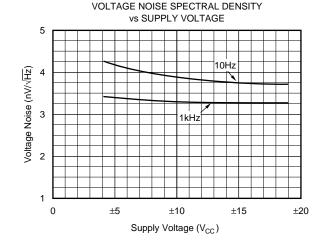
# **TYPICAL CHARACTERISTICS**

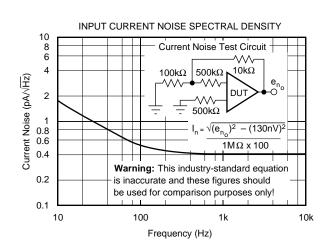
At T<sub>A</sub> = +25°C,  $\pm$ V<sub>CC</sub> =  $\pm$ 15VDC, unless otherwise noted.

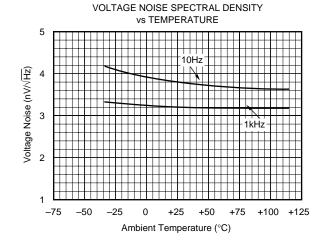




TOTAL INPUT VOLTAGE NOISE SPECTRAL DENSITY vs SOURCE RESISTANCE 100 80 60 R₁ 40 0-1 Voltage Noise (nV/VHz) 0  $\sqrt{}$ 20 R₁  $R_{SOURCE} = 2 \times R$ 10 8 6 10Hz 4 Resistor Noise Only 1kHz 2 1 100 1k 10k Source Resistance (Ω)





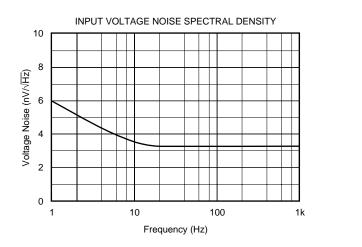


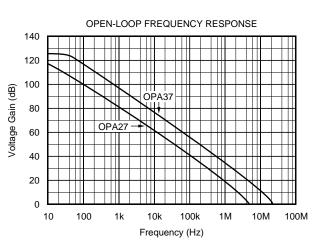


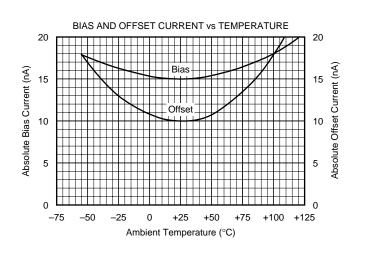


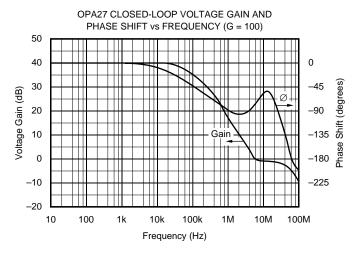
# **TYPICAL CHARACTERISTICS (Cont.)**

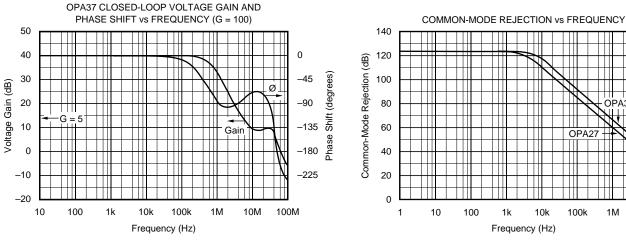
At T<sub>A</sub> = +25°C,  $\pm$ V<sub>CC</sub> =  $\pm$ 15VDC, unless otherwise noted.

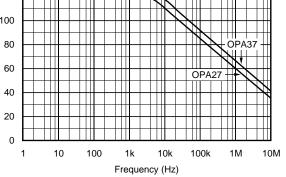










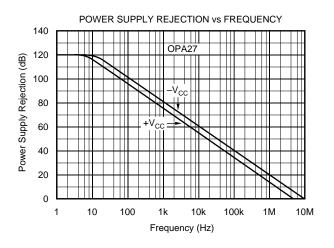


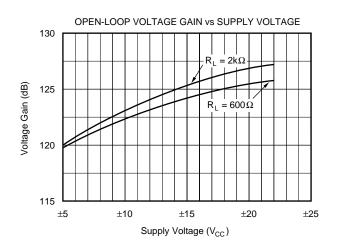


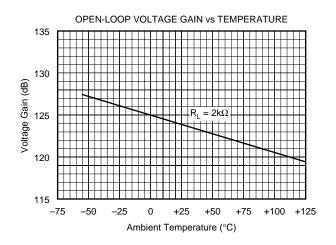


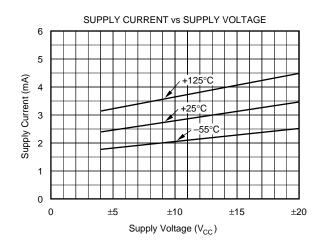
## **TYPICAL CHARACTERISTICS (Cont.)**

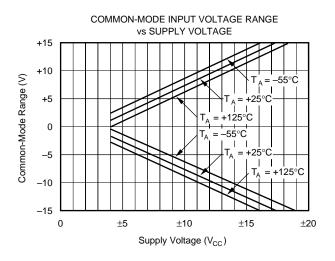
At T<sub>A</sub> = +25°C,  $\pm$ V<sub>CC</sub> =  $\pm$ 15VDC, unless otherwise noted.











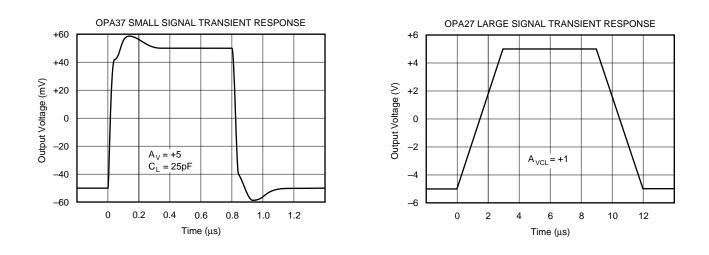
**OPA27 SMALL SIGNAL TRANSIENT RESPONSE** +60 +40 Output Voltage (mV) +20 0 -20  $A_{VCL} = +1$  $C_L = 15$ pF -40 -60 0 0.5 1 1.5 2 2.5 Time (µs)

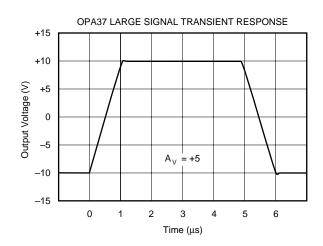




# **TYPICAL PERFORMANCE CURVES**

At T<sub>A</sub> = +25°C,  $\pm$ V<sub>CC</sub> = ±15VDC, unless otherwise noted.









## **APPLICATIONS INFORMATION**

### OFFSET VOLTAGE ADJUSTMENT

The OPA27 and OPA37 offset voltages are laser-trimmed and require no further trim for most applications. Offset voltage drift will not be degraded when the input offset is nulled with a 10k $\Omega$  trim potentiometer. Other potentiometer values from 1k $\Omega$  to 1M $\Omega$  can be used, but V<sub>OS</sub> drift will be degraded by an additional 0.1 $\mu$ V/°C to 0.2 $\mu$ V/°C. Nulling large system offsets by use of the offset trim adjust will degrade drift performance by approximately 3.3 $\mu$ V/°C per millivolt of offset. Large system offsets can be nulled without drift degradation by input summing.

The conventional offset voltage trim circuit is shown in Figure 3. For trimming very small offsets, the higher resolution circuit shown in Figure 4 is recommended.

The OPA27 and OPA37 can replace 741-type operational amplifiers by removing or modifying the trim circuit.

### THERMOELECTRIC POTENTIALS

The OPA27 and OPA37 are laser-trimmed to microvolt-level input offset voltages, and for very-low input offset voltage drift.

Careful layout and circuit design techniques are necessary to prevent offset and drift errors from external thermoelectric potentials. Dissimilar metal junctions can generate small EMFs if care is not taken to eliminate either their sources (lead-to-PC, wiring, etc.) or their temperature difference (see Figure 11).

Short, direct mounting of the OPA27 and OPA37 with close spacing of the input pins is highly recommended. Poor layout can result in circuit drifts and offsets which are an order of magnitude greater than the operational amplifier alone.

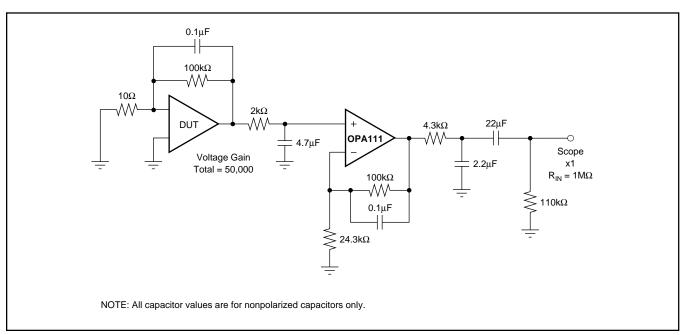


FIGURE 1. 0.1Hz to 10Hz Noise Test Circuit.

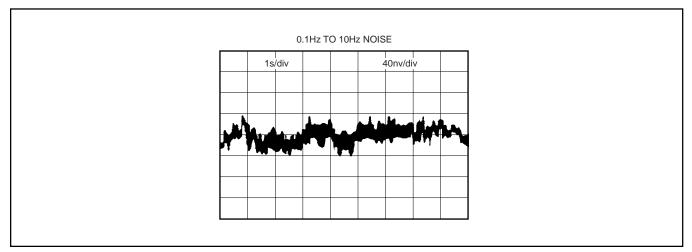


FIGURE 2. Low Frequency Noise.



#### NOISE: BIPOLAR VERSUS FET

Low-noise circuit design requires careful analysis of all noise sources. External noise sources can dominate in many cases, so consider the effect of source resistance on overall operational amplifier noise performance. At low source impedances, the lower voltage noise of a bipolar operational amplifier is superior, but at higher impedances the high current noise of a bipolar amplifier becomes a serious liability. Above about  $15k\Omega$ , the OPA111 low-noise FET operational amplifier is recommended for lower total noise than the OPA27, as shown in Figure 5.

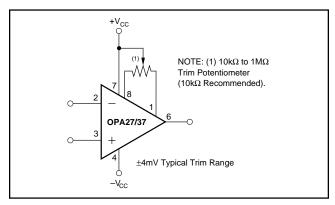


FIGURE 3. Offset Voltage Trim.

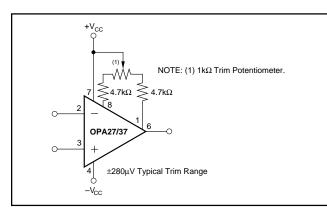


FIGURE 4. High Resolution Offset Voltage Trim.

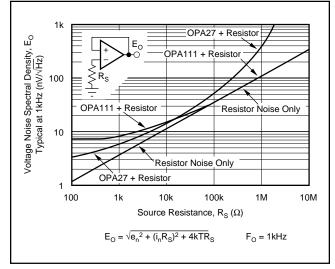


FIGURE 5. Voltage Noise Spectral Density Versus Source Resistance.

#### COMPENSATION

Although internally compensated for unity-gain stability, the OPA27 may require a small capacitor in parallel with a feedback resistor ( $R_F$ ) which is greater than  $2k\Omega$ . This capacitor will compensate the pole generated by  $R_F$  and  $C_{IN}$  and eliminate peaking or oscillation.

#### INPUT PROTECTION

Back-to-back diodes are used for input protection on the OPA27 and OPA37. Exceeding a few hundred millivolts differential input signal will cause current to flow, and without external current limiting resistors, the input will be destroyed.

Accidental static discharge, as well as high current, can damage the amplifier's input circuit. Although the unit may still be functional, important parameters such as input offset voltage, drift, and noise may be permanently damaged, as will any precision operational amplifier subjected to this abuse.

Transient conditions can cause feedthrough due to the amplifier's finite slew rate. When using the OPA27 as a unity-gain buffer (follower) a feedback resistor of  $1k\Omega$  is recommended, as shown in Figure 6.

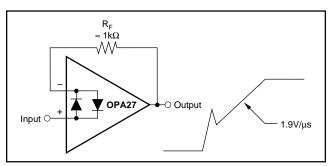


FIGURE 6. Pulsed Operation.

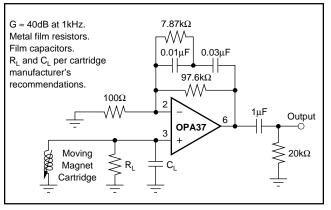


FIGURE 7. Low-Noise RIAA Preamplifier.

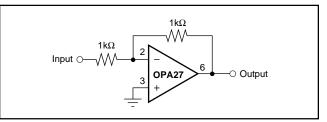


FIGURE 8. Unity-Gain Inverting Amplifier.





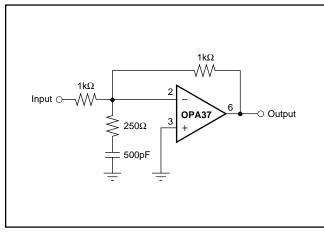


FIGURE 9. High Slew Rate Unity-Gain Inverting Amplifier.

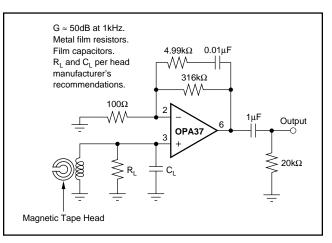


FIGURE 10. NAB Tape Head Preamplifier.

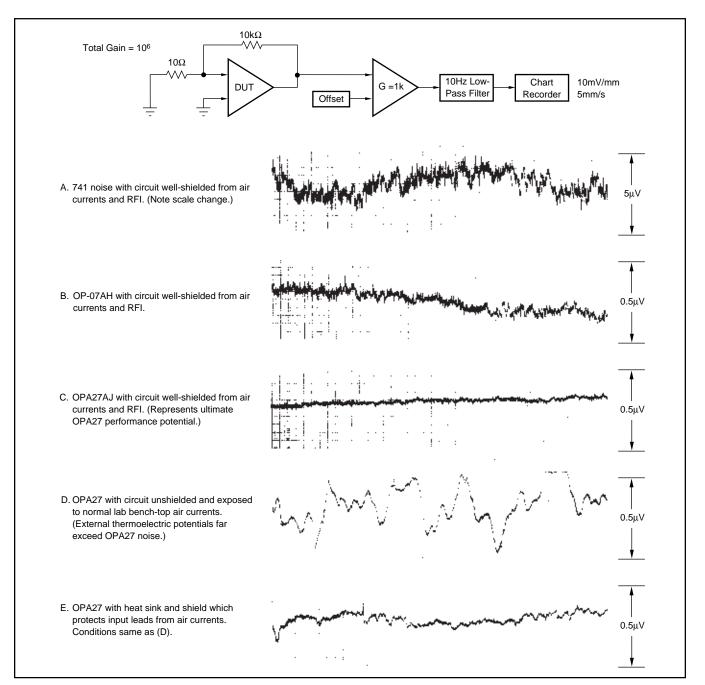


FIGURE 11. Low Frequency Noise Comparison.





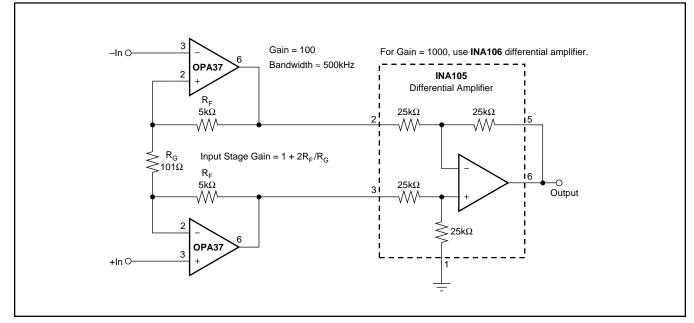


FIGURE 12. Low Noise Instrumentation Amplifier.

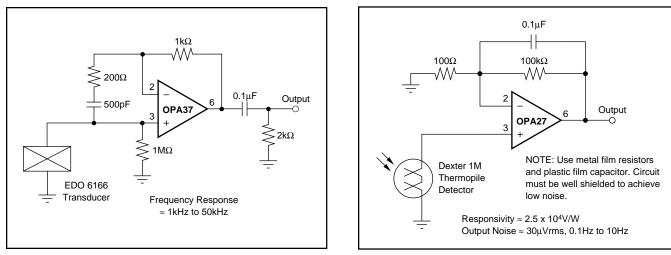
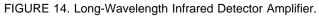


FIGURE 13. Hydrophone Preamplifier.



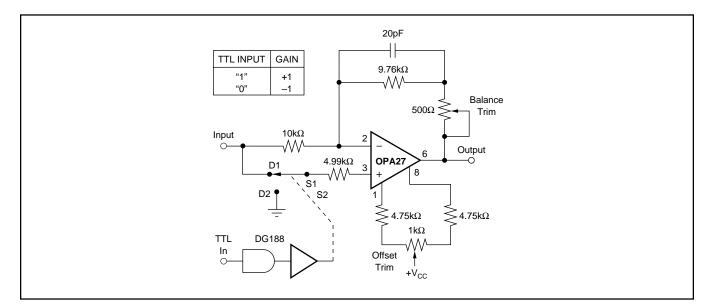


FIGURE 15. High Performance Synchronous Demodulator.





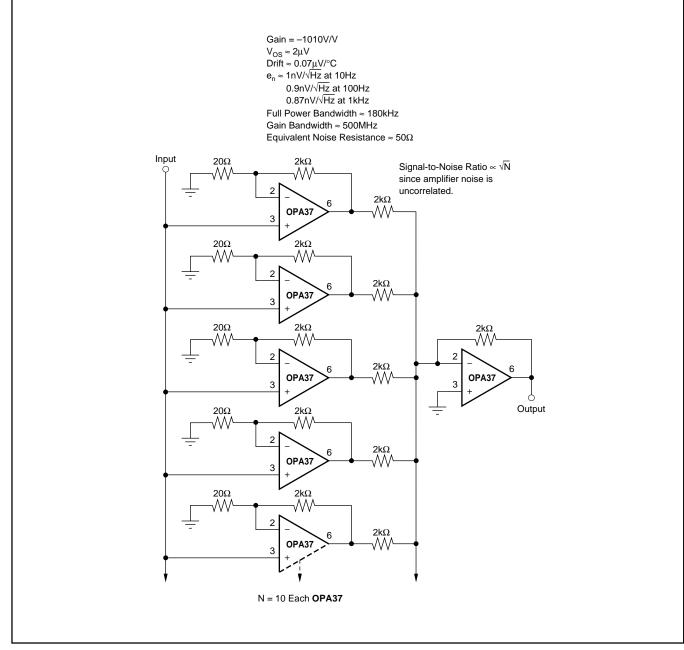


FIGURE 16. Ultra-Low Noise "N"-Stage Parallel Amplifier.



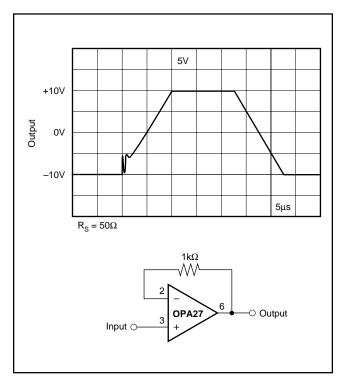


FIGURE 17. Unity-Gain Buffer.

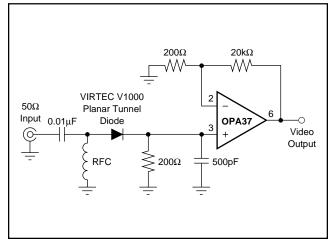


FIGURE 19. RF Detector and Video Amplifier.

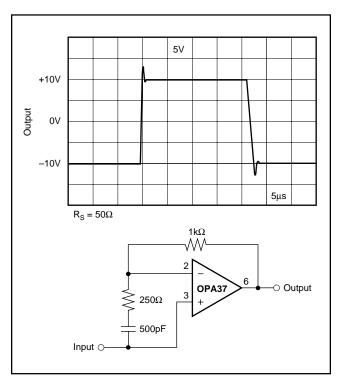


FIGURE 18. High Slew Rate Unity-Gain Buffer.

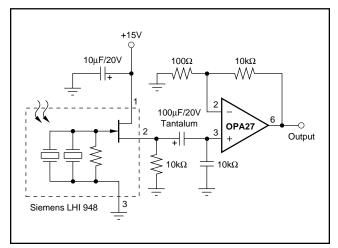


FIGURE 20. Balanced Pyroelectric Infrared Detector.

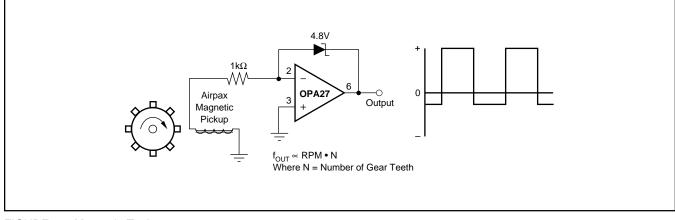


FIGURE 21. Magnetic Tachometer.



TEXAS INSTRUMENTS www.ti.com

### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	n MSL Peak Temp <sup>(3)</sup>
OPA27GP	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
OPA27GPG4	ACTIVE	PDIP	Ρ	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
OPA27GU	ACTIVE	SOIC	D	8	100	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA27GU/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA27GU/2K5E4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA27GUE4	ACTIVE	SOIC	D	8	100	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA27GUG4	ACTIVE	SOIC	D	8	100	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA37GP	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
OPA37GPG4	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
OPA37GU	ACTIVE	SOIC	D	8	100	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA37GU/2K5	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA37GU/2K5G4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR
OPA37GUE4	ACTIVE	SOIC	D	8	100	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on



incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*Al	dimensions are nominal												
	Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	OPA27GU/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
	OPA37GU/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



## PACKAGE MATERIALS INFORMATION

11-Mar-2008

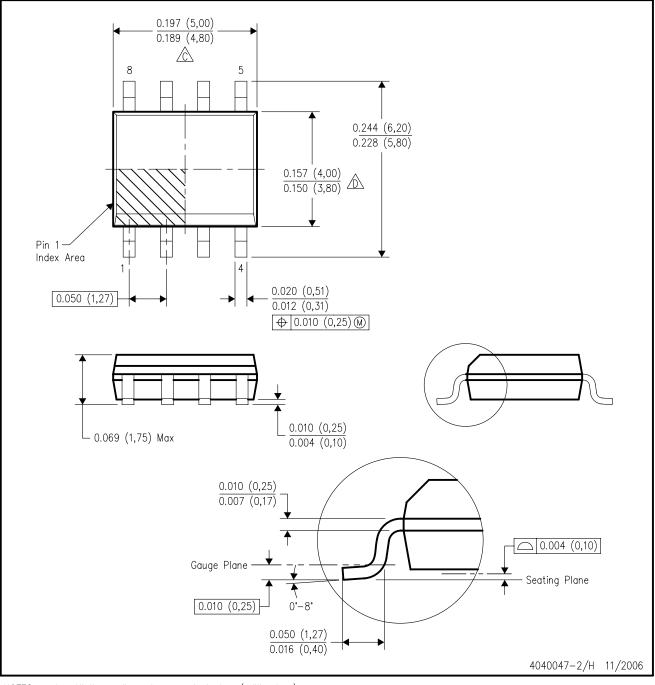


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA27GU/2K5	SOIC	D	8	2500	346.0	346.0	29.0
OPA37GU/2K5	SOIC	D	8	2500	346.0	346.0	29.0

D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.

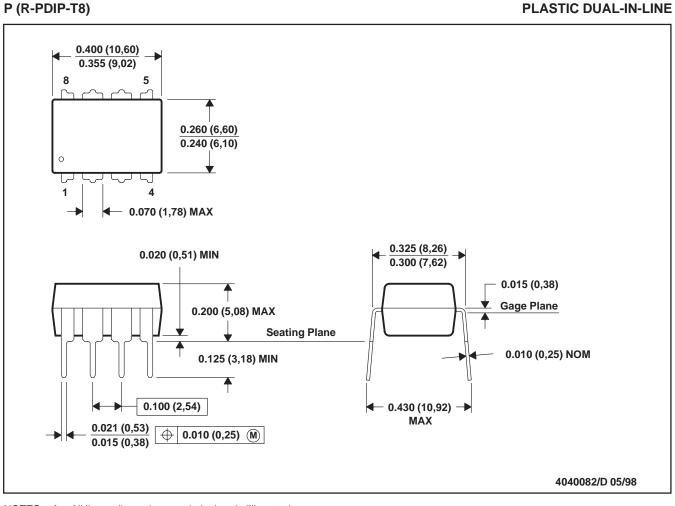
Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.

E. Reference JEDEC MS-012 variation AA.



### **MECHANICAL DATA**

MPDI001A - JANUARY 1995 - REVISED JUNE 1999



- NOTES: A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg\_info.htm



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Clocks and Timers	www.ti.com/clocks	Digital Control	www.ti.com/digitalcontrol
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Telephony	www.ti.com/telephony
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2008, Texas Instruments Incorporated